NSN 5961-01-307-7627

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End Application:

6625-01-018-8584 generator, signal

Internal Configuration:

Field effect

Semiconductor Material:

Silicon

Current Rating Per Characteristic:

3.00 milliamperes zero-gate-voltage drain current and 10.00 milliamperes zero-gate-voltage drain current and 1.00 nanoamperes reverse

gate current with all other terminals short-circuit to source, junction-gate

Power Rating Per Characteristic:

300.0 milliwatts total device dissipation

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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